imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Transistors with Built-in Resistor DRA9124T0L

DRA9124T0L Silicon PNP epitaxial planar type

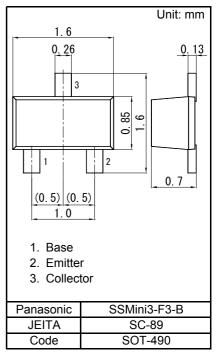
For digital circuits Complementary to DRC9124T DRA5124T in SSMini3 type package

Features

- · High forward current transfer ratio hFE with excellent linearity
- Low collector-emitter saturation voltage Vce(sat)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: LH

Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)



Internal Connection							
R ₁ B ○		•C					
		oE					
Resistance value	R1	22	kΩ				

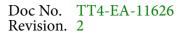
■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	VCBO	-50	V	
Collector-emitter voltage (Base open)	VCEO	-50	V	
Collector current	IC	-100	mA	
Total power dissipation	PT	125	mW	
Junction temperature	Tj	150	°C	
Operating ambient temperature	Topr	-40 to +85	°C	
Storage temperature	Tstg	-55 to +150	С°	

■ Electrical Characteristics Ta = 25 °C ± 3 °C

Symbol	Conditions Min		Тур	Max	Unit					
VCBO	IC = -10 μA, IE = 0	-50			V					
VCEO	IC = -2 mA, IB = 0	-50			V					
ICBO	VCB = -50 V, IE = 0			-0.1	μA					
ICEO	VCE = -50 V, IB = 0			-0.5	μA					
IEBO	VEB = -6 V, IC = 0			-0.01	mA					
hFE	VCE = -10 V, IC = -5 mA	160		460	-					
VCE(sat)	IC = -10 mA, IB = -0.5 mA			-0.25	V					
Vi(on)	VCE = -0.2 V, IC = -5 mA	-1.8			V					
Vi(off)	VCE = -5 V, IC = -100 μA			-0.4	V					
R1		-30%	22	+30%	kΩ					
	Symbol VCBO ICBO ICEO IEBO hFE VCE(sat) Vi(on) Vi(off)	Symbol Conditions VCBO IC = -10 μ A, IE = 0 VCEO IC = -2 mA, IB = 0 ICBO VCB = -50 V, IE = 0 ICEO VCE = -50 V, IB = 0 IEBO VEB = -6 V, IC = 0 hFE VCE = -10 V, IC = -5 mA VCE(sat) IC = -10 mA, IB = -0.5 mA Vi(on) VCE = -5 V, IC = -100 μ A	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Symbol Conditions Min Typ VCBO IC = -10 μ A, IE = 0 -50 VCEO IC = -2 mA, IB = 0 -50 ICBO VCB = -50 V, IE = 0 -50 ICEO VCE = -50 V, IE = 0 -50 IEBO VEB = -6 V, IC = 0 -50 hFE VCE = -10 V, IC = -5 mA 160 VCE(sat) IC = -10 mA, IB = -0.5 mA -1.8 Vi(on) VCE = -5 V, IC = -100 μ A -1.8	SymbolConditionsMinTypMaxVCBOIC = -10 μ A, IE = 0-50-50-50VCEOIC = -2 mA, IB = 0-50-50-0.1ICBOVCB = -50 V, IE = 0-0.1-0.1ICEOVCE = -50 V, IB = 0-0.5-0.5IEBOVEB = -6 V, IC = 0-0.01hFEVCE = -10 V, IC = -5 mA160460VCE(sat)IC = -10 mA, IB = -0.5 mA-1.8-0.25Vi(on)VCE = -5 V, IC = -100 μ A-0.4					

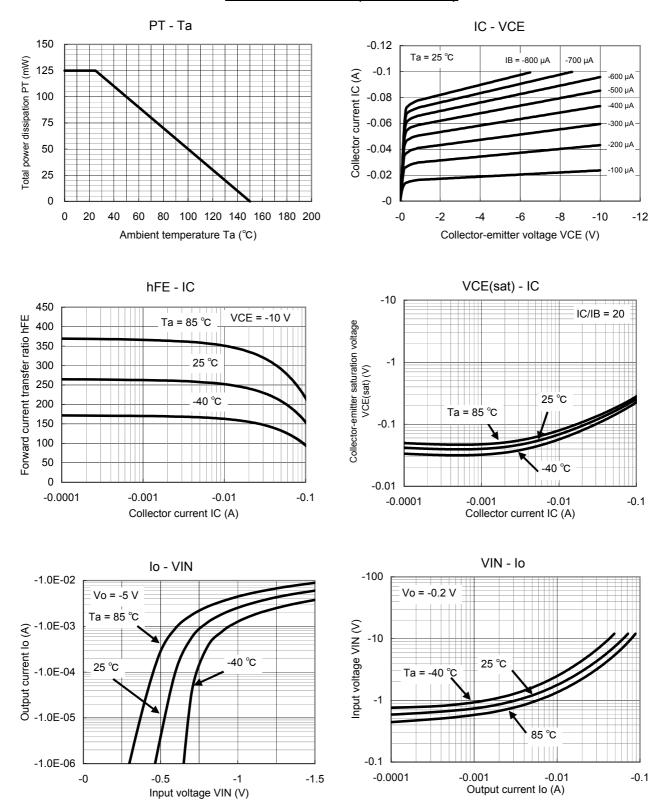
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.



Transistors with Built-in Resistor DRA9124T0L



Technical Data (reference)



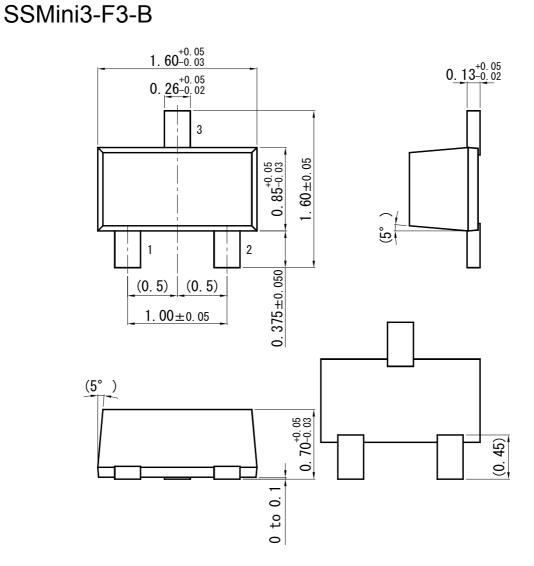
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Established : 2009-10-16 Revised : 2014-02-27

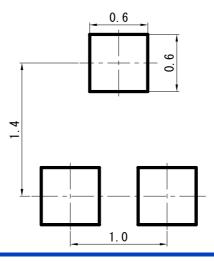


Transistors with Built-in Resistor DRA9124T0L

Unit: mm



Land Pattern (Reference) (Unit: mm)



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